

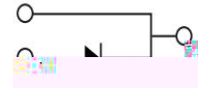
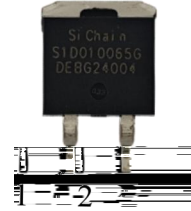
S1D010065G



TriQSiC™ 650V Silicon Carbide Schottky Diode G1

Features

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-
-
-
-
-



Benefits

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-
-
-
-



Applications

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-
-
-

Table 1 Key performance and package parameters

Type	V _{RRM}	I _F	Q _C	Marking	Package



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650V SiC Schottky Diode

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FEU

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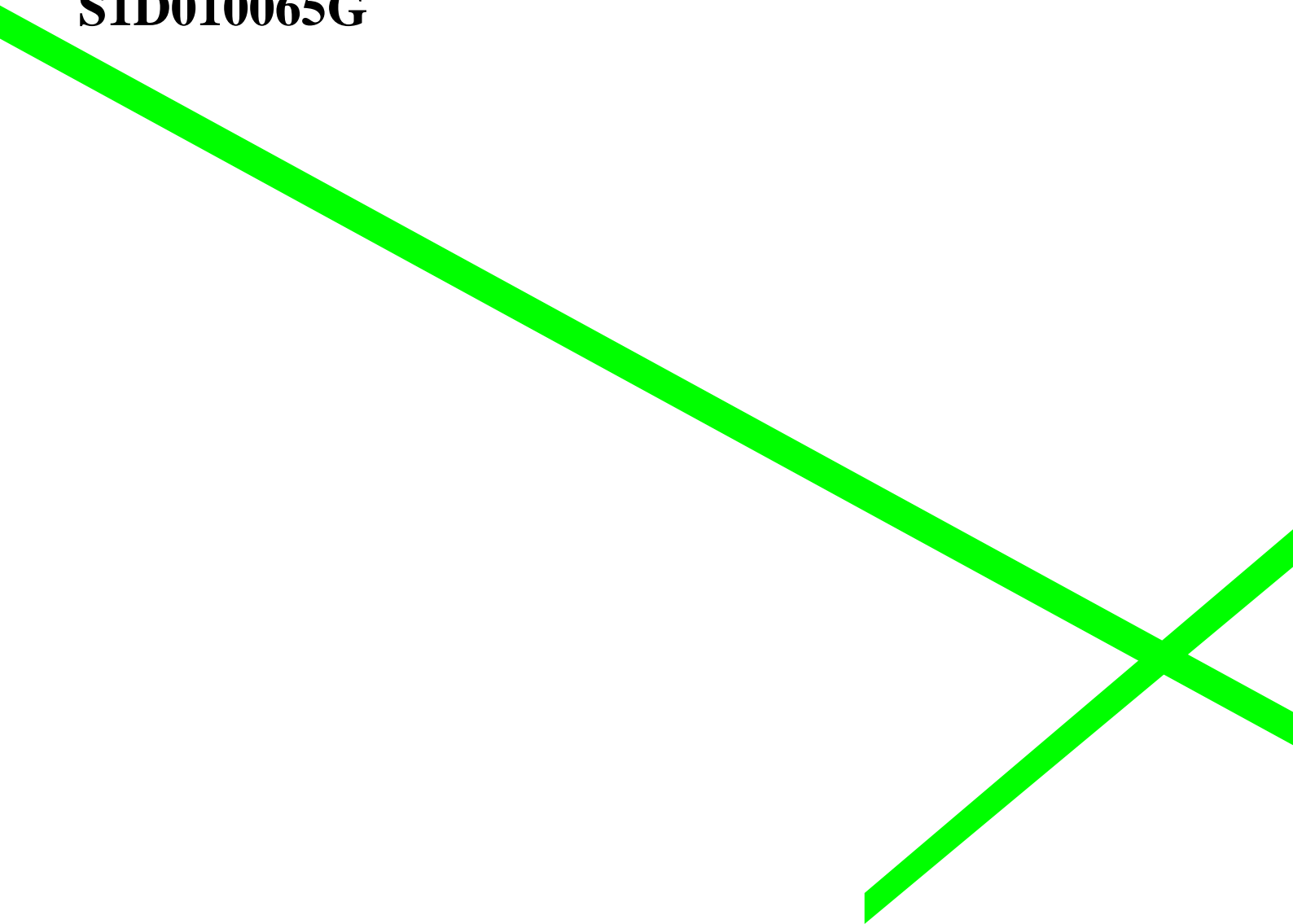
650V SiC Schottky Diode

1 Maximum ratings

Table 2 Maximum rating

Symbol	Parameter	Value	Unit	Test Conditions	Note
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650V SiC Schottky Diode

Revision history

Document version	Date of release	Description of changes
V01_00	2025-04-29	--

Attention

RoHS

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